

BC817 series

45 V, 500 mA NPN general-purpose transistors

Rev. 8 — 1 July 2022

Product data sheet

1. General description

NPN general-purpose transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package			PNP complement
	Nexperia	JEDEC	JEITA	
BC817	SOT23 TO-236AB	TO-236AB	-	BC807
BC817-16				BC807-16
BC817-25				BC807-25
BC817-40				BC807-40

2. Features and benefits

- · High current
- · Three current gain selections

3. Applications

· General-purpose switching and amplification

4. Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
V _{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C		-	-	45	V		
I _C	collector current	T _{amb} = 25 °C		-	-	500	mA		
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C		-	-	1	Α		
h _{FE}	DC current gain								
	BC817	V_{CE} = 1 V; I_{C} = 100 mA T_{amb} = 25 °C	[1]	100	-	600			
	BC817-16		[1]	100	-	250			
	BC817-25		[1]	160	-	400			
	BC817-40		[1]	250	-	600			

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



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5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	С
2	E	emitter		
3	С	collector		B—
				Ė
			1	sym123

6. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
BC817	TO-236AB	Plastic surface-mounted package; 3 leads	SOT23				
BC817-16							
BC817-25							
BC817-40							

7. Marking

Table 5. Marking

Type number	Marking code[1]
BC817	6D%
BC817-16	6A%
BC817-25	6B%
BC817-40	6C%

^{[1] % =} placeholder for manufacturing site code

2/13

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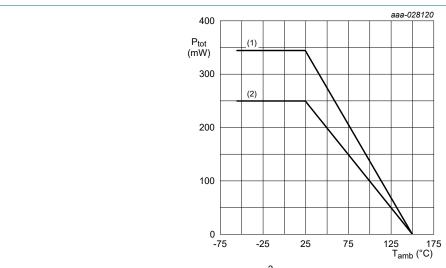
8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter; T _{amb} = 25 °C	-	50	V
V_{CEO}	collector-emitter voltage	open base; T _{amb} = 25 °C	-	45	V
V_{EBO}	emitter-base voltage	open collector; T _{amb} = 25 °C	-	5	V
Ic	collector current	T _{amb} = 25 °C	-	500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	1	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms; T _{amb} = 25 °C	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1		250	mW
		[3 [2		345	mW
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	150	°C
T _{stg}	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) FFR4 PCB, single-sided copper; 1 cm²
- (2) FR4 PCB, single-sided copper; standard footprint

Fig. 1. Power derating curves

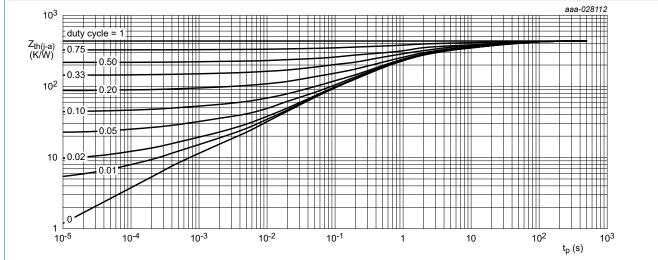
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9. Thermal characteristics

Table 7. Thermal characteristics

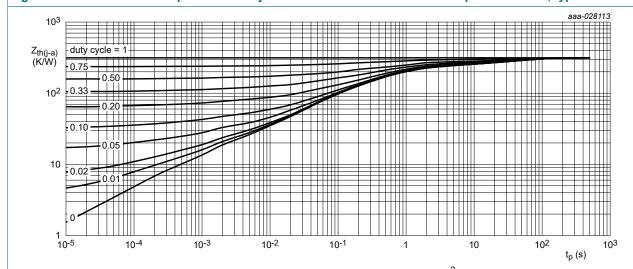
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] [2]	-	-	500	K/W
			[3] [2]	-	-	362	K/W

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- [2] Valid for all available selection groups.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm².



FR4 PCB, single-sided, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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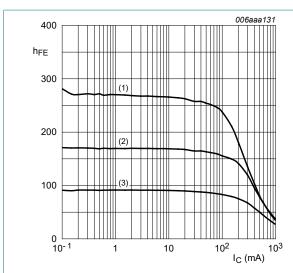
10. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A; T _{amb} = 25 °C		50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 10 mA; I _E = 0 A; T _{amb} = 25 °C		45	-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = 100 μA; I _C = 0 A; T _{amb} = 25 °C		5	-	-	V
I _{CBO}	collector-base	V _{CB} = 20 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	cut-off current	V _{CB} = 20 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain						'
	BC817	V _{CE} = 1 V; I _C = 100 mA; T _{amb} = 25 °C	[1]	100	-	600	
	BC817-16		[1]	100	-	250	
	BC817-25		[1]	160	-	400	
	BC817-40		[1]	250	-	600	
h _{FE}	DC current gain	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	-	-	700	mV
V_{BE}	base-emitter voltage	V _{CE} = 1 V; I _C = 500 mA; T _{amb} = 25 °C	[1] [2]	-	-	1.2	V
f⊤	transition frequency	V _{CE} = 5 V; I _C = 10 mA; f = 100 MHz; T _{amb} = 25 °C		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	3	-	pF
	· · · · · · · · · · · · · · · · · · ·						

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \; \mu \text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \; \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$

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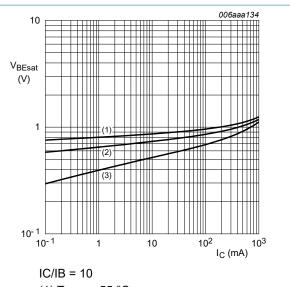
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 4. BC817-16: DC current gain as a function of collector current; typical values

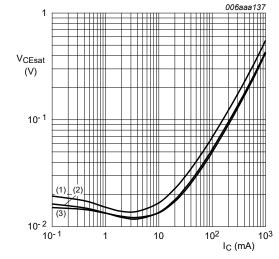


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. BC817-16: Base-emitter saturation voltage as a function of collector current; typical values

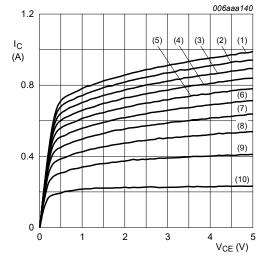


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 6. BC817-16: Collector-emitter saturation voltage as a function of collector current; typical values



T_{amb} = 25 °C

 $(1) I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$

(6) $I_B = 8.0 \text{ mA}$

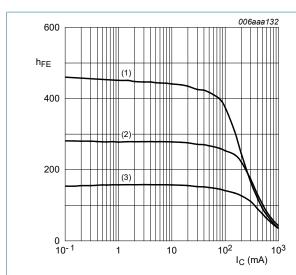
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$ (10) $I_B = 1.6 \text{ mA}$

Fig. 7. BC817-16: Collector current as a function of collector-emitter voltage; typical values

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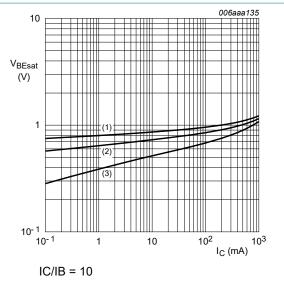
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 8. BC817-25: DC current gain as a function of collector current; typical values

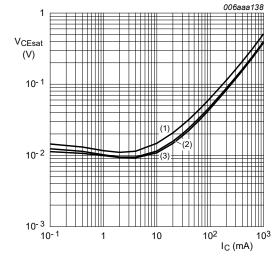


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 9. BC817-25: Base-emitter saturation voltage as a function of collector current; typical values

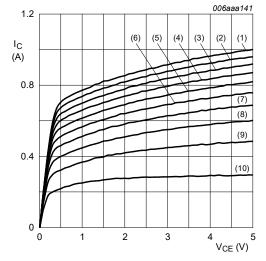


$$IC/IB = 10$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 10. BC817-25: Collector-emitter saturation voltage as a function of collector current; typical values



(1)
$$I_B = 13.0 \text{ mA}$$

(2)
$$I_B = 11.7 \text{ mA}$$

(3)
$$I_B = 10.4 \text{ mA}$$

(4)
$$I_B = 9.1 \text{ mA}$$

$$(5) I_B = 7.8 \text{ mA}$$

(6)
$$I_B = 6.5 \text{ mA}$$

(7)
$$I_B = 5.2 \text{ mA}$$

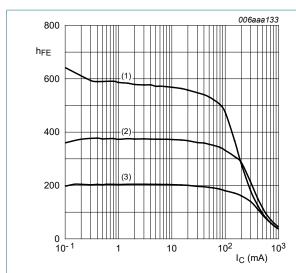
(8)
$$I_B = 3.9 \text{ mA}$$

(9)
$$I_B = 2.6 \text{ mA}$$

$$(10) I_B = 1.3 mA$$

Fig. 11. BC817-25: Collector current as a function of collector-emitter voltage; typical values

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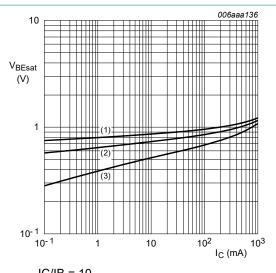
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC817-40: DC current gain as a function of collector current; typical values

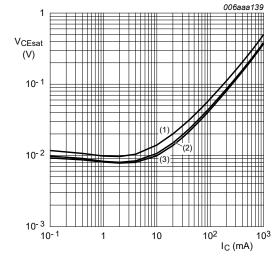


(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC817-40: Base-emitter saturation voltage as a function of collector current; typical values

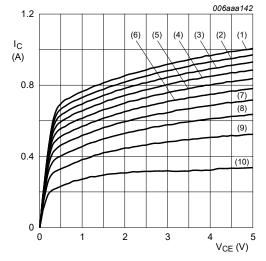


IC/IB = 10

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55$$
 °C

Fig. 14. BC817-40: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = 12.0 \text{ mA}$

 $(2) I_B = 10.8 \text{ mA}$

(3) $I_B = 9.6 \text{ mA}$

 $(4) I_B = 8.4 \text{ mA}$

 $(5) I_B = 7.2 mA$

(6) $I_B = 6.0 \text{ mA}$

 $(7) I_B = 4.8 \text{ mA}$

(8) $I_B = 3.6 \text{ mA}$

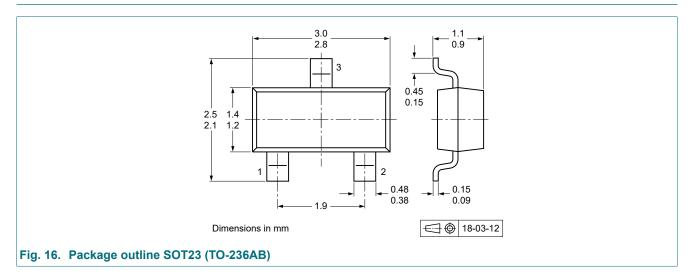
(9) $I_B = 2.4 \text{ mA}$

 $(10) I_B = 1.2 mA$

Fig. 15. BC817-40: Collector current as a function of collector-emitter voltage; typical values

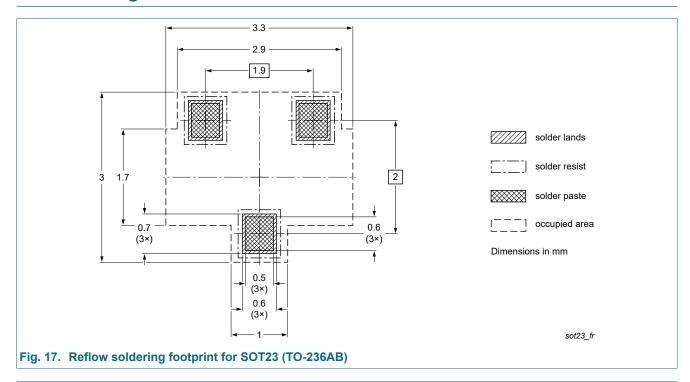
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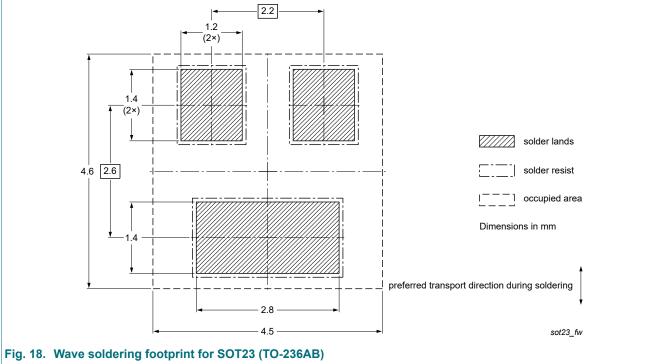
11. Package outline



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12. Soldering





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13. Revision history

Table 9. Revision history

Tubic 5. Itevision mistory						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
BC817_SER v.8	20220701	Product data sheet	-	BC817_SER v.7		
Modifications:	 Product(s) changed to non-automotive qualification. Please refer to nexperia.com automotive (-Q) product alternative(s). 					
BC817_SER v.7	20180615	Product data sheet	-	BC817_BC817W_BC327 v.6		
BC817_BC817W_BC337 v.6	20091117	Product data sheet	-	BC817_BC817W_BC337 v.5		
BC817_BC817W_BC337 v.5	20050221	Product data sheet	CPCN200302007F CPCN200405006F	BC817 v.4 BC817W v.4 BC337 v.3		
BC817 v.4	20040116	Product Specification	-	BC817 v.3		
BC817W_SER v.4	19990518	Product Specification	-	BC817W_SER v.3		
BC337 v.3	19990415	Product Specification	-	BC337_338_CNV v.2		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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